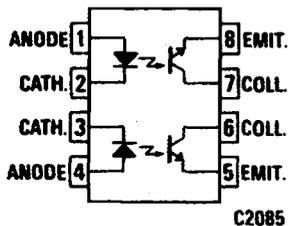
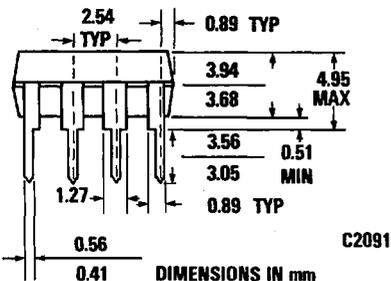
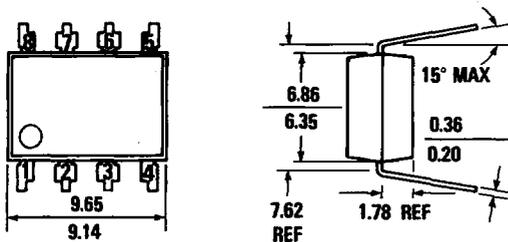


**MCT6 MCT62
MCT61 MCT66**

PACKAGE DIMENSIONS



Equivalent Circuit

DESCRIPTION

The MCT6X optoisolators have two channels for high density applications. For four channel applications, two-packages fit into a standard 16-pin DIP socket. Each channel is an NPN silicon planar phototransistor optically coupled to a gallium arsenide infrared emitting diode.

FEATURES

- Two isolated channels per package
- Two packages fit into a 16 lead DIP socket
- 2500 volt isolation
- Choice of 4 current transfer ratios
- Underwriters Laboratory (U.L.) recognized File E50151

APPLICATIONS

- AC Line/Digital Logic—Isolate high voltage transients
- Digital Logic/Digital Logic—Eliminate spurious grounds
- Digital Logic/AC Triac Control—Isolate high voltage transients
- Twisted pair line receiver—Eliminate ground loop feedthrough
- Telephone/Telegraph line receiver—Isolate high voltage transients
- High Frequency Power Supply Feedback Control—Maintain floating ground
- Relay contact monitor—Isolate floating grounds and transients
- Power Supply Monitor—Isolate transients

ABSOLUTE MAXIMUM RATINGS

| | | |
|-----------------------------------|----------------------------|-----------------------------|
| Storage temperature | | -55°C to 150°C |
| Operating temperature | | -55°C to 100°C |
| Lead temperature | (soldering, 10 sec.) | 250°C |
| TOTAL INPUT | | |
| Power dissipation at 25°C ambient | | 100 mW |
| Derate linearly from 25°C | | 1.3 mW/°C |
| COUPLED | | |
| Input to output breakdown voltage | .. | 2500 volts V _{RMS} |
| Total package power dissipation | | |
| @ 25°C ambient | | 400 mW |
| Derate linearly from 25°C | | 5.33 mW/°C |

INPUT DIODE (each channel)

| | | |
|--|-------|-------|
| Forward current | | 60 mA |
| Reverse voltage | | 3.0 V |
| Peak forward current (1 μs pulse, 300 pps) | | 3 A |

OUTPUT TRANSISTOR (each channel)

| | | |
|----------------------------------|-------|---------|
| Power dissipation @ 25°C ambient | | 150 mW |
| Derate linearly from 25°C | | 2 mW/°C |
| Collector current | | 30 mA |

ELECTRO-OPTICAL CHARACTERISTICS

(25°C Free Air Temperature Unless Otherwise Specified)

INDIVIDUAL COMPONENT CHARACTERISTICS

| CHARACTERISTICS | SYMBOL | MIN. | TYP. | MAX. | UNITS | TEST CONDITION |
|---|------------|------|------|------|---------------|----------------------------------|
| INPUT DIODE | | | | | | |
| Rated forward voltage | V_F | | 1.25 | 1.50 | V | $I_F = 20 \text{ mA}$ |
| Reverse voltage | V_R | 3.0 | 25 | | V | $I_R = 10 \text{ } \mu\text{A}$ |
| Reverse current | I_R | | .001 | 10 | μA | $V_R = 3.0 \text{ V}$ |
| Junction capacitance | C_J | | 50 | | pF | $V_F = 0 \text{ V}$ |
| OUTPUT TRANSISTOR ($I_F = 0$) | | | | | | |
| Breakdown voltage, collector to emitter | BV_{CEO} | 30 | 85 | | V | $I_C = 1.0 \text{ mA}$ |
| Breakdown voltage, emitter to collector | BV_{ECO} | 6 | 13 | | V | $I_E = 100 \text{ } \mu\text{A}$ |
| Leakage current, collector to emitter | I_{CEO} | | 5 | 100 | nA | $V_{CE} = 10 \text{ V}$ |
| Capacitance collector to emitter | C_{CE} | | 8 | | pF | $V_{CE} = 0 \text{ V}$ |

TRANSFER CHARACTERISTICS

| CHARACTERISTICS | SYMBOL | MIN. | TYP. | MAX. | UNITS | TEST CONDITION |
|---|---------------|------|------|------|-------|--|
| COUPLED | | | | | | |
| DC current transfer ratio (I_C/I_F) = CTR | | | | | | |
| MCT6 | | 20 | | | % | $V_{CE} = 10 \text{ V}, I_F = 10 \text{ mA}$ |
| MCT61 | | 50 | | | % | $V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$ |
| MCT62 | | 100 | | | % | $V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$ |
| MCT66 | | 6 | | | % | $V_{CE} = 10 \text{ V}, I_F = 10 \text{ mA}$ |
| Saturation voltage—collector to emitter MCT6, 61, 62 | $V_{CE(SAT)}$ | | 0.2 | 0.4 | V | $I_C = 2 \text{ mA}, I_F = 16 \text{ mA}$ |
| MCT66 | | | 0.2 | 0.4 | V | $I_C = 2 \text{ mA}, I_F = 40 \text{ mA}$ |

TRANSFER CHARACTERISTICS

| CHARACTERISTICS | SYMBOL | MIN. | TYP. | MAX. | UNITS | TEST CONDITION |
|--|--------|------|------|------|---------------|--|
| SWITCHING TIMES, OUTPUT TRANSISTOR | | | | | | |
| Non-saturated rise time, fall time (Note 3) | | | 2.4 | | μs | $I_C = 2 \text{ mA}, V_{CE} = 10 \text{ V}, R_L = 100\Omega$ |
| Non-saturated rise time, fall time (Note 3) | | | 15 | | μs | $I_C = 2 \text{ mA}, V_{CE} = 10 \text{ V}, R_L = 1\text{K}\Omega$ |
| Saturated turn-on time (from 5.0V to 0.8V) | | | 5 | | μs | $R_L = 2\text{K}\Omega, I_F = 40 \text{ mA}$ |
| Saturated turn-off time (from saturation to 2.0V) | | | 25 | | μs | $R_L = 2\text{K}\Omega, I_F = 40 \text{ mA}$ |
| Bandwidth B_w | | | 150 | | kHz | $I_C = 2 \text{ mA}, V_{CC} = 10 \text{ V}, R_L = 100\Omega$ |

ISOLATION CHARACTERISTICS

| CHARACTERISTICS | SYMBOL | MIN. | TYP. | MAX. | UNITS | TEST CONDITION |
|---|--------------|-----------|-----------|------|-----------|--|
| Isolation voltage | $BV_{(I-O)}$ | 2500 | | | V_{RMS} | $t = 1 \text{ minute}$ |
| Isolation resistance MCT6X— | $R_{(I-O)}$ | 10^{11} | 10^{12} | | Ω | $V_{I-O} = 500 \text{ VDC}$ |
| Breakdown voltage—channel-to-channel MCT6X | | | 500 | | VDC | Relative humidity = 40% $f = 1 \text{ MHz}$ |
| Capacitance between channels | | | 0.4 | | pF | |

MCT6 TYPICAL ELECTRO-OPTICAL CHARACTERISTIC CURVES

(25°C Free Air Temperature Unless Otherwise Specified)

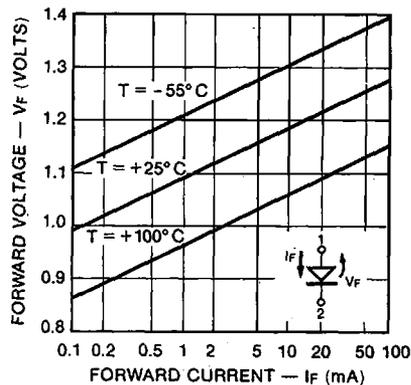


Fig. 1. Forward Voltage vs. Current

C1686

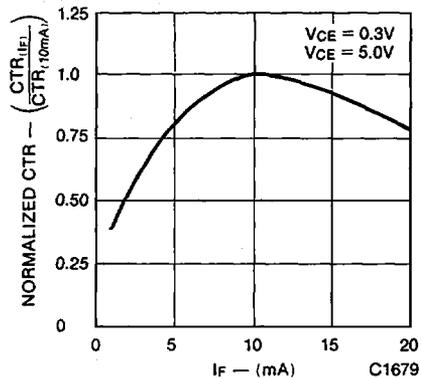


Fig. 2. Normalized CTR vs. Forward Current

C1679

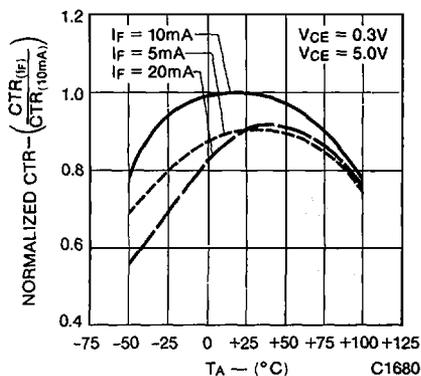


Fig. 3. Normalized CTR vs. Temperature

C1680

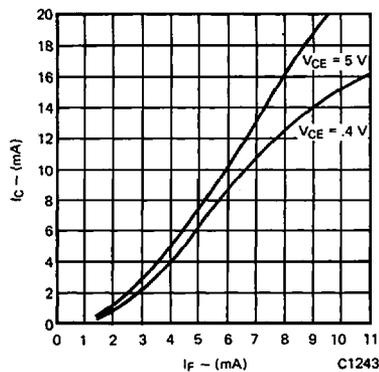


Fig. 4. Collector Current vs. Forward Current

C1243

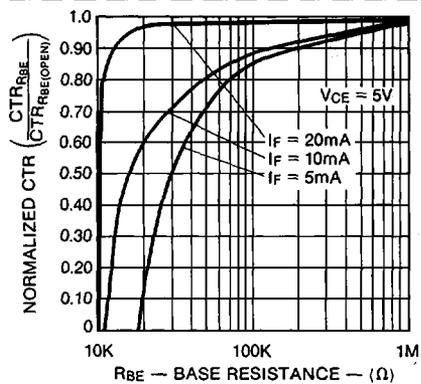


Fig. 5. CTR vs. RBE (Unsaturated)

C1681

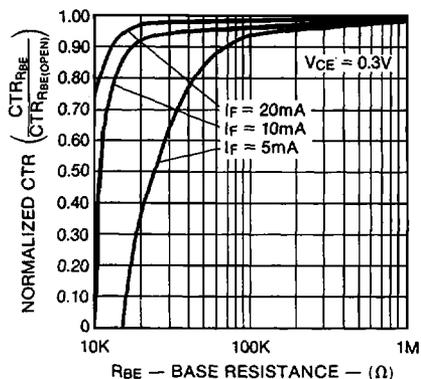


Fig. 6. CTR vs. RBE (Saturated)

C1682

MCT6 MCT61 MCT62 MCT66

MCT6 TYPICAL ELECTRO-OPTICAL CHARACTERISTIC CURVES
(25°C Free Air Temperature Unless Otherwise Specified) (Cont'd)

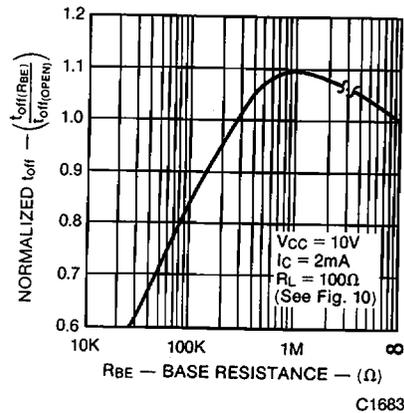


Fig. 7. Normalized T_{OFF} vs. RBE

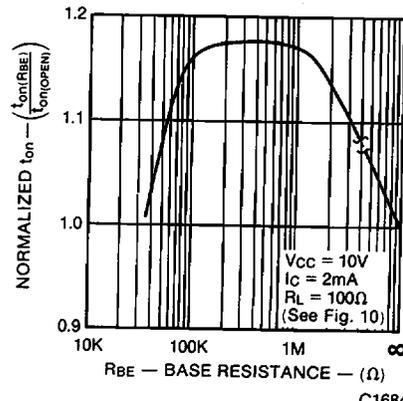


Fig. 8. Normalized T_{ON} vs. RBE

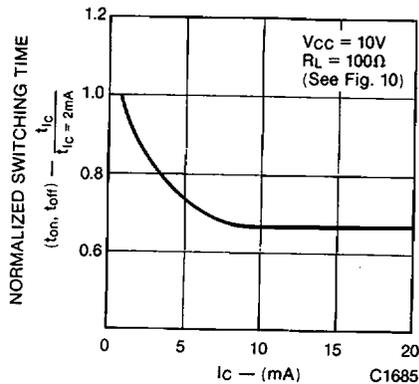


Fig. 9. Switching Time vs. I_C

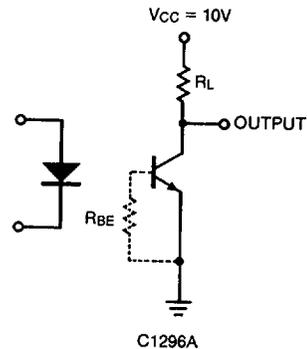


Fig. 10. Switching Time Test Circuit

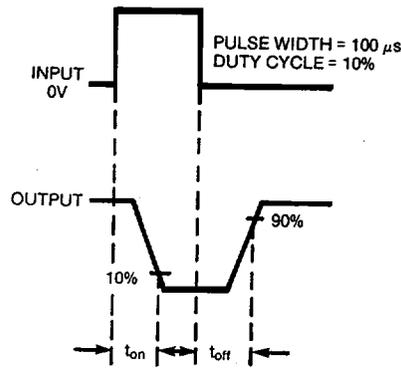
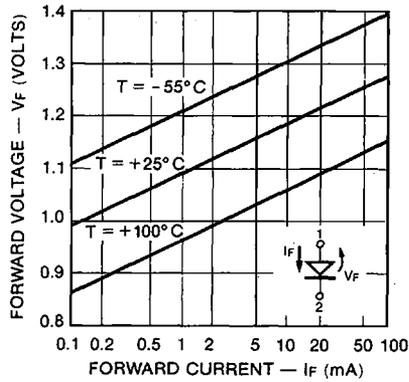


Fig. 11. Switching Time Waveforms

MCT6 MCT61 MCT62 MCT66

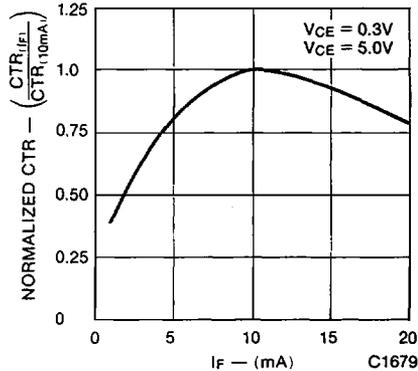
MCT66 TYPICAL ELECTRO-OPTICAL CHARACTERISTIC CURVES

(25°C Free Air Temperature Unless Otherwise Specified)



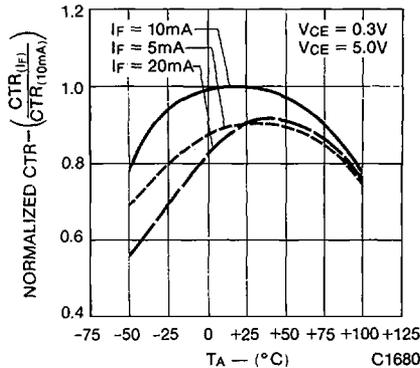
C1686

Fig. 1. Forward Voltage vs. Current



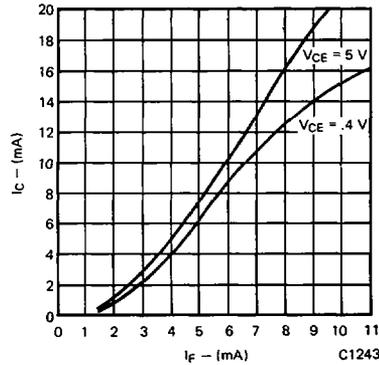
C1679

Fig. 2. Normalized CTR vs. Forward Current



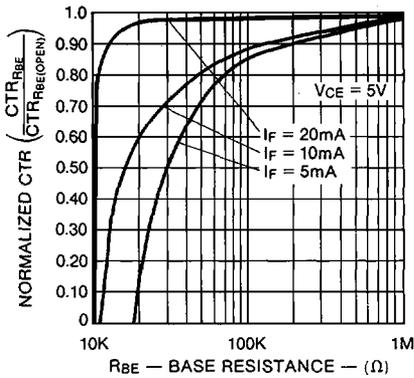
C1680

Fig. 3. Normalized CTR vs. Temperature



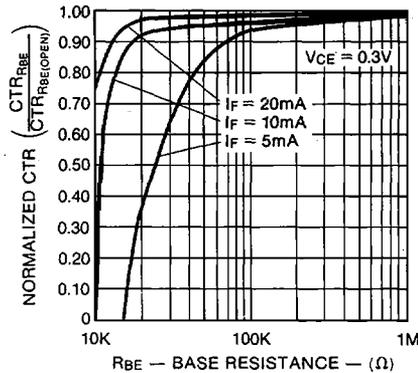
C1243

Fig. 4. Collector Current vs. Forward Current



C1681

Fig. 5. CTR vs. RBE (Unsaturated)



C1682

Fig. 6. CTR vs. RBE (Saturated)

MCT6 MCT61 MCT62 MCT66

MCT66 TYPICAL ELECTRO-OPTICAL CHARACTERISTIC CURVES

(25°C Free Air Temperature Unless Otherwise Specified) (Cont'd)

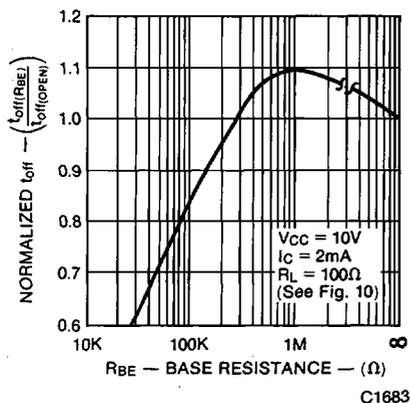


Fig. 7. Normalized T_{OFF} vs. RBE

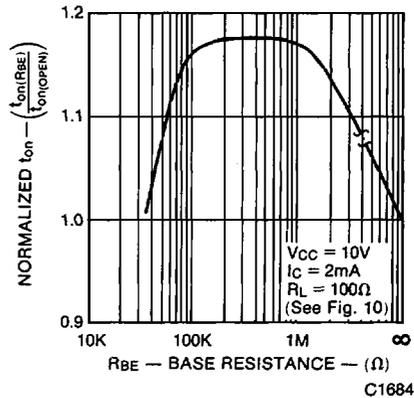


Fig. 8. Normalized T_{ON} vs. RBE

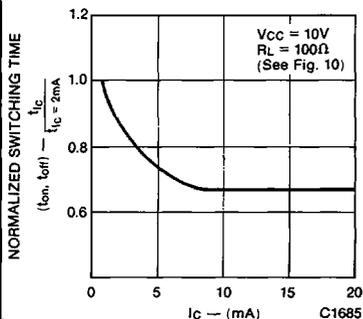


Fig. 9. Switching Time vs. I_C

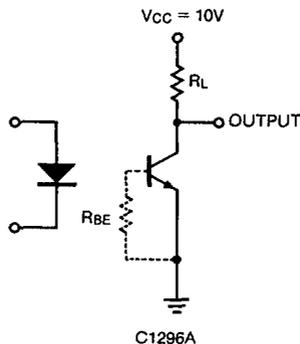


Fig. 10. Switching Time Test Circuit

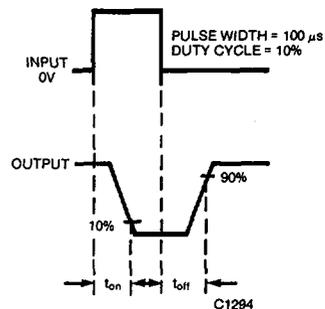


Fig. 11. Switching Time Waveforms

NOTES

- Normalized CTR degradation = $\frac{CTR_{\sigma} \cdot CTR}{CTR_0}$
- The current transfer ratio (I_C/I_P) is the ratio of the detector collector current to the LED input current with V_{CE} at 10 volts.
- The frequency at which i_c is 3 dB down from the 1 kHz value.
- Rise time (t_r) is the time required for the collector current to increase from 10% of its final value to 90%. Fall time (t_f) is the time required for the collector current to decrease from 90% of its initial value to 10%.

MCT6 MCT61 MCT62 MCT66